



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **BANBA, Seiichi et al.**

Group Art Unit: 2817

Serial No.: **09/813,303**

Examiner: **SHINGLETON, Michael**

Filed: **March 21, 2001**

P.T.O. Confirmation No.: 1802

For: **HIGH FREQUENCY CIRCUIT WITH THIN FILM RESISTOR (as amended)**

10/a  
SMW  
5-70-8

**AMENDMENT UNDER 37 CFR §1.111**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, Virginia 22313-1450

May 2, 2003

Sir:

In response to the Office Action dated **January 2, 2003**, please amend the above-identified application as follows:

**IN THE TITLE:**

Please amend the title of the invention, in its entirety, so as to read as follows:

-- HIGH FREQUENCY CIRCUIT WITH THIN FILM RESISTOR --

**IN THE CLAIMS:**

Please amend claim 1 as indicated below:

1. (Amended) A high frequency circuit comprising:

a transistor having a first terminal receiving an input signal and having a second terminal and a third terminal;

a first circuit connected to said second terminal of said transistor; and

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